NSN 5962-01-131-8100

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View Online at https://aerobasegroup.com/nsn/5962-01-131-8100 **Body Length:** Between 0.750 inches and 0.785 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.145 inches and 0.185 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Display grp 76301 **Features Provided:** Hermetically sealed and monolithic and schottky and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 5.5 volts power source **Time Rating Per Chacteristic:** 30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Ram **Memory Capacity:** Unknown **Test Data Document:** 09344-pc73571 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 printed circuit Shelf Life:

Demilitarization: Yes - demil/mli

Unit Of Measure:

N/a

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